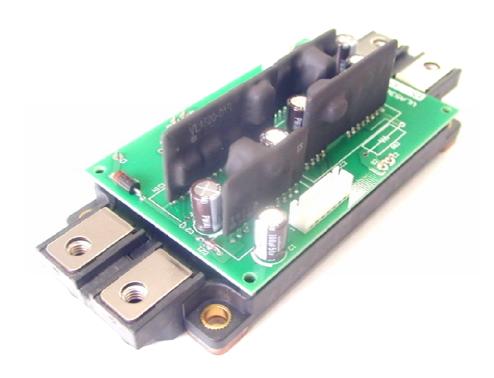
(PRELIMINARY)

IGBT Gate Drive Unit VLA536-01R



Apr.07,'09



(PRELIMINARY)

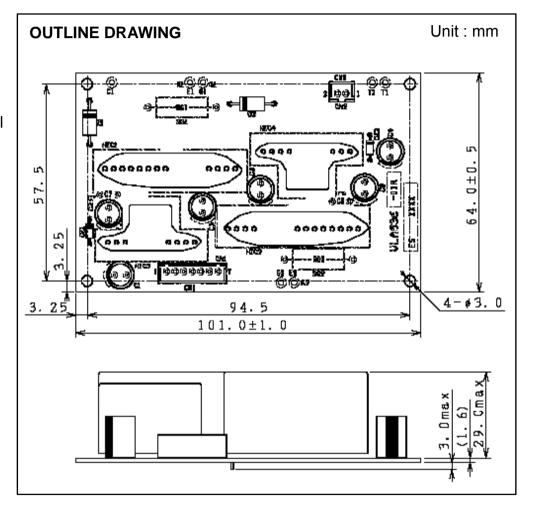
FEATURE

- >Possible to mount on the IGBT package (2 in 1 package)
- >Built in the isolated DC-DC converter for gate drive
- >Built in short circuit protection
- >Electrical isolation voltage is 2500Vrms (for 1 minute)
- >Two way power supply system for drivers and input signal (VD=15V, VIN=5V)
- >CMOS compatible input interface

RECOMMENDED IGBT MODULES

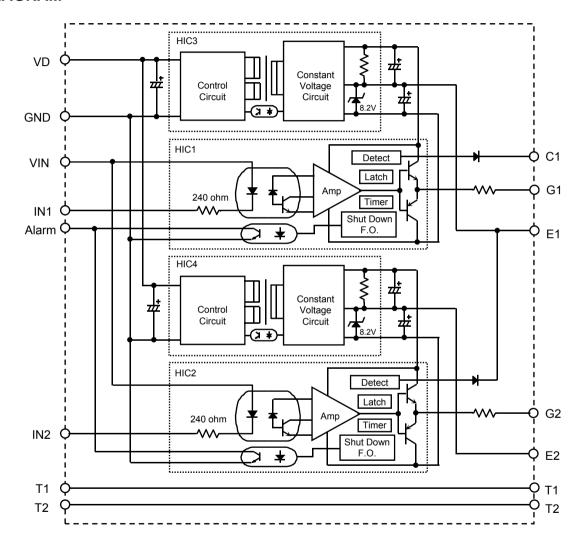
MITSUBISHI NX series IGBT modules VCES = 600V series ~ 400A class

VCES = 1200V series ~ 450A class



BLOCK DIAGRAM

(PRELIMINARY)



MAXIMUM RATINGS

(unless otherwise noted, Ta=25C)

(PREL	IMINA	RY)
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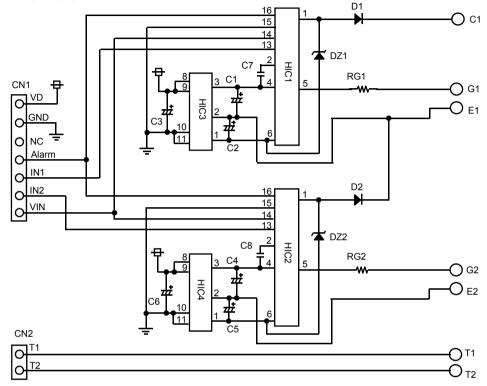
Symbol	Parameter	Conditions	Ratings	Unit
VD	Supply voltage	DC	18	V
VI	Input signal voltage	Applied between VIN - IN1,2 50% Duty cycle, Pulse width 1ms	-1 ~ +7	٧
IOHP	Onto month occurrent	Dula a midlih Oma	-5	Α
IOLP	Gate peak current	Pulse width 2us	5	Α
Viso	Isolation voltage	Sine wave voltage 60Hz, for 1min	2500	Vrms
Topr	Operating temperature	No condensation allowable	-20 ~ 70	deg C
Tstg	Storage temperature	No condensation allowable	-25 ~ 85	deg C
lalm	Alarm output current	-	10	mA
Valm	Alarm pin voltage	-	50	V
Idrive	Gate drive current	Gate average current (Per one circuit)	TBD	mA

ELECTRICAL CHARACTERISTICS

(unless otherwise noted, Ta=25C, VD=15V)

Symbol	Parameter	Conditions	Limits			Unit
Cymbol	i didiliotoi	Sorialions	Min	Тур	Max	01110
VD	Supply voltage	Recommended range	12	15	18	V
VIN	Pull-up voltage on input side	Recommended range	4.75	5	5.25	V
IIH	Input signal current	Recommended range	10	13	16	mA
f	Switching frequency	Recommended range	-	-	20	kHz
RG	Gate resistance	Recommended range	2	-	-	Ω
lalm	Alarm output current	Recommended range	-	-	5	mA
VOH	Plus bias voltage	-	TBD	TBD	TBD	V
VOL	Minus bias voltage	-	TBD	TBD	TBD	V
tPLH	"L-H" propagation time	IIH = 13mA	0.2	0.45	0.8	us
tPHL	"H-L" propagation time	IIH = 13mA	0.2	0.4	0.7	us
t_timer	Timer	Between start and clear (under input signal "OFF")	1	1.4	2	ms
tdalm	Alarm delay time	lalm=2.5mA	-	6.5	10	us
VSC	SC detect threshold voltage	IGBT collector voltage	TBD	TBD	TBD	V

INNER CIRCUIT



(PRELIMINARY)

CN1		
PinN.o.	Pin name	
1	VD	
2	GND	
3	NC	
4	Alarm	
5	IN1	
6	IN2	
7	VIN	

CN	CN2		
Pin N.o.	Pin name		
1	T1		
2	T2		

Parts list	(Reference)	
HIC1,2	VLA520-01R	ISAHAYA
HIC3,4	VLA106-15252	ISAHAYA
DZ1,2	30V, 500mW	

D1,2 RP1H SanKen
C1 ~ 6 100uF, 50V Low inpedance
C7,8 10pF ~ 50pF , 50V TDK FK28 type

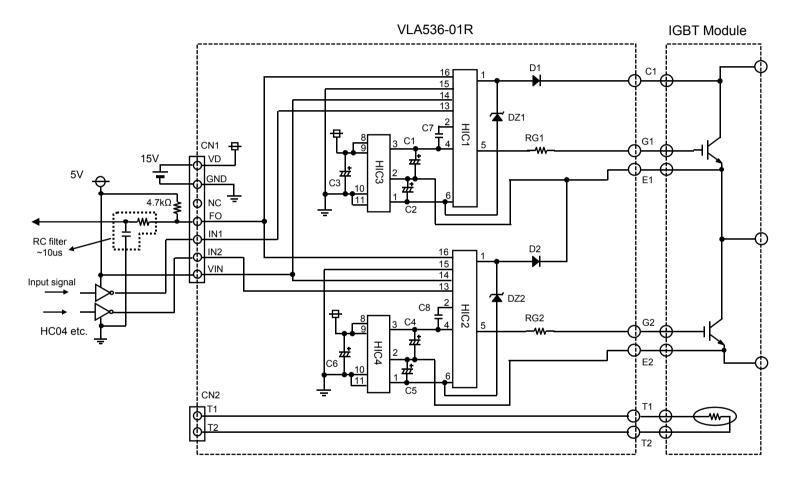
RG1,2 3W class CN1 B7B-XH-A JST CN2 B2B-XH-A JST *1) Gate Resistor is not installed at the time of shipment. Please solder the chosen resistor.

*2) C7,8 is not installed at the time of shipment. Please solder the chosen condenser if needed. (Rough guide 10 ~ 50pF, 50V, ceramic)



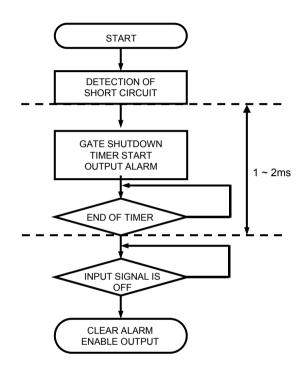
APPLICATION EXAMPLE

(PRELIMINARY)



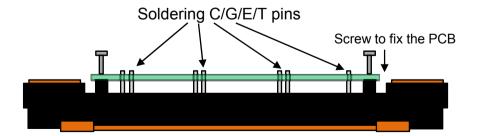
OPERATION FLOW ON DETECTING SHORT CIRCUIT

(PRELIMINARY)



- (1)In case the gate voltage is "H" and the collector voltage is high, the gate driver will recognize the circuit as short circuit and immediately reduce the gate voltage.(Slow shut down) Besides, put out an alarm sign which inform that protection circuit is operating.
- (2)The protection circuit return to ordinary condition if input sign is OFF when the predetermined time(1~2ms) passed.(OFF period is needed more than 40us.)

INSTALLATION OF THE PCB ON IGBT MODULE





(PRELIMINARY)

Keep safety first in your circuit designs!

ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary circuits, (2) use of non-farmable material or (3) prevention against any malfunction or mishap.

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